Electronic Supporting Information (ESI)

Increased photocurrent response in Nb-doped TiO_2 nanotubes

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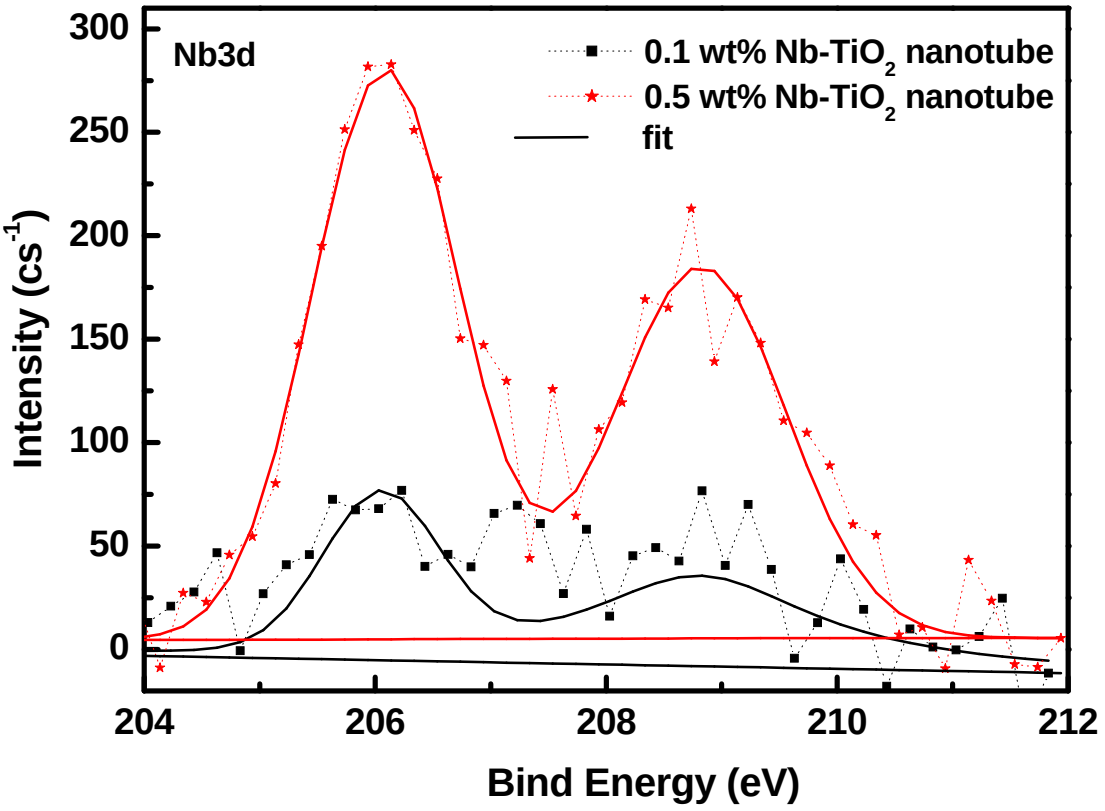

Fig. S1 XPS of Nb3d peaks in 0.1 wt% Nb-doped and 0.5 wt% Nb-doped TiO_2 nanotube layers. Quantitative evaluation shows the content in the oxide to be close to the nominal alloy composition (0.1 wt% Nb is however close to detective limit of XPS).

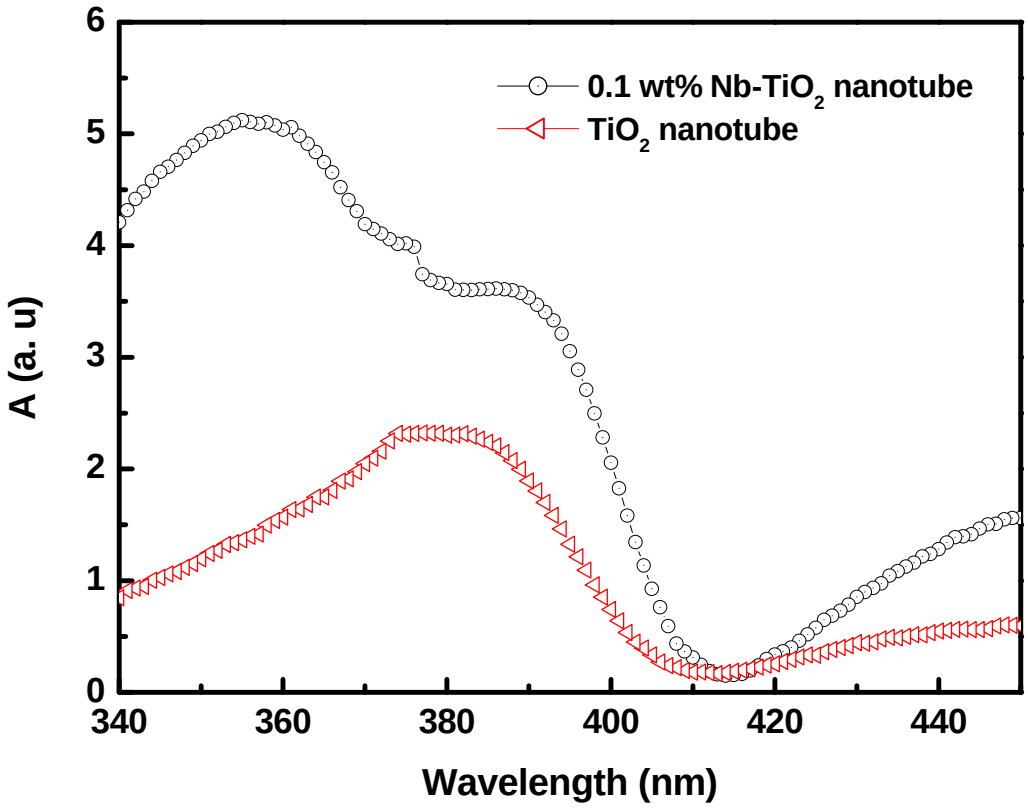

Fig. S2 Light absorbance for pure TiO_2 and 0.1 wt% Nb-doped TiO_2 nanotube layers with 2μm thickness annealed at 650^{o}C, acquired using diffuse reflectance measurements. It shows the absorbance of the Nb-doped material to be higher than for plain TiO_2.